TOSHIBA Photocoupler Photo Relay

# TLP597G

### Cordless Telephone

**PBX** 

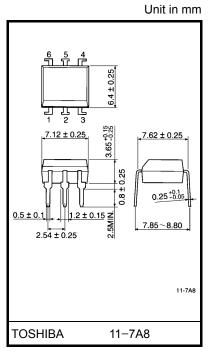
#### Modem

The TOSHIBA TLP597G consists of a gallium arsenide infrared emitting diode optically coupled to a photo–MOSFET in a six lead plastic DIP package (DIP6).

The TLP597G is a bi–directional switch which can replace mechanical relay in many applications.

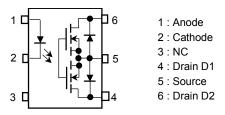
- Peak off-state voltage: 350V (min.)
- Trigger LED current: 3mA (max.)
- On-state current: 120mA (max.) (A connection)
- On-state resistance: 35Ω (max.) (A connection)
- Isolation voltage: 2500V<sub>rms</sub> (min.)
- Isolation thickness: 0.4mm (min.)
- UL recognized: UL1577, file no. E67349
- BSI approved: BS EN60065: 2002, certificate no. 8275
   BS EN60950-1: 2002, certificate no. 8276
- Option (D4) type

: TUV approved: DIN EN 60747-5-2, Certificate no. 40011913

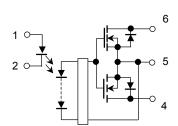


Weight: 0.4 g

### Pin Configuration (top view)



#### **Schematic**



### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit		
	Forward current	lF	50	mA		
	Forward current derating (Ta	ΔI <sub>F</sub> / °C	-0.5	mA / °C		
Ē	Peak forward current (100 µs	pulse, 100 pps)	I <sub>FP</sub>	1	Α	
_	Reverse voltage		V <sub>R</sub>	5	V	
	Junction temperature	Tj	125	°C		
	Off-state output terminal volt	V <sub>OFF</sub>	350	V		
	On-state RMS current	A connection		120		
		B connection	I <sub>ON</sub>	120	mA	
ctor		C connection		160		
Detector	On–state current derating (Ta ≥ 25°C)	A connection		-1.2		
		B connection	ΔI <sub>ON</sub> / °C	-1.2	mA / °C	
	(14 = 2 = 7)	C connection		-1.6		
	Junction temperature		Tj	125	°C	
Stora	ge temperature range	T <sub>stg</sub>	-55~125	°C		
Operating temperature range			T <sub>opr</sub>	<b>−40~85</b>	°C	
Lead soldering temperature (10 s)			T <sub>sol</sub>	260	°C	
Isolat	ion voltage (AC, 1 min., R.H.≤	BVS	2500	V <sub>rms</sub>		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

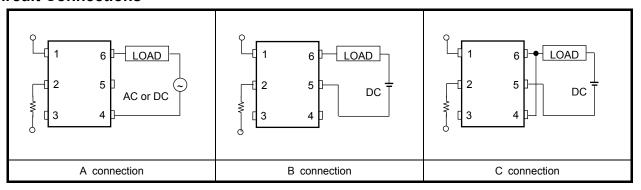
(Note 1): Device considered a two–terminal device: Pins 1, 2 and 3 shorted together and pins 4, 5 and 6 shorted together.

# **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	$V_{DD}$	_	_	280	V
Forward current	lF	5	7.5	25	mA
On-state current	I <sub>ON</sub>	_	_	120	mA
Operating temperature	T <sub>opr</sub>	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Circuit Connections**



# Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μA
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30	_	pF
Detector	Off-state current	l <sub>OFF</sub>	V <sub>OFF</sub> = 350 V			1	μΑ
	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz	1	40	1	pF

# **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current		I <sub>FT</sub>	I <sub>ON</sub> = 120 mA	_	1	3	mA
	A connection		I <sub>ON</sub> = 120 mA, I <sub>F</sub> = 5 mA	_	22	35	Ω
On–state Resistance		R <sub>ON</sub>	I <sub>ON</sub> = 20 ~ 120mA, I <sub>F</sub> = 5 mA	_	26	40	Ω
Resistance	B connection	-	I <sub>ON</sub> = 120 mA, I <sub>F</sub> = 5 mA	_	13	20	Ω
	C connection		I <sub>ON</sub> = 160 mA, I <sub>F</sub> = 5 mA	_	7	10	Ω

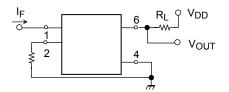
# **Isolation Characteristics (Ta = 25°C)**

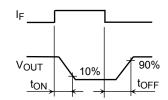
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H.≤ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
		AC, 1 minute	2500	_	_	V
Isolation voltage	$BV_S$	AC, 1 second, in oil	_	5000	_	V <sub>rms</sub>
		DC, 1 minute, in oil	_	5000	_	Vdc

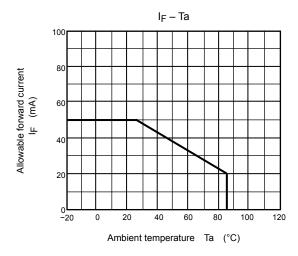
# **Switching Characteristics (Ta = 25°C)**

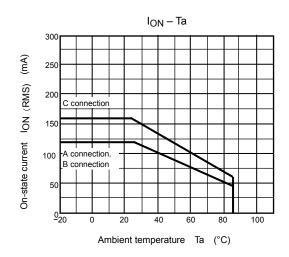
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t <sub>ON</sub>	$R_L = 200\Omega$ (Note 2)	_	0.3	1	me
Turn-off time	toff	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	_	0.1	1	ms

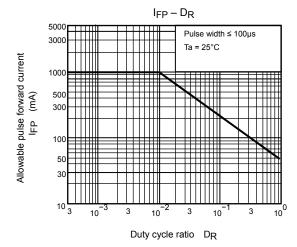
(Note 2): Switching time test circuit

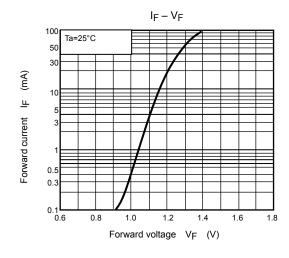


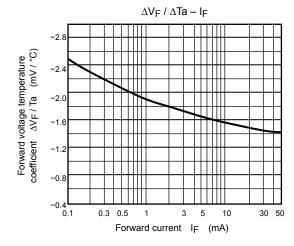


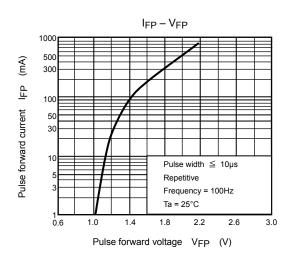




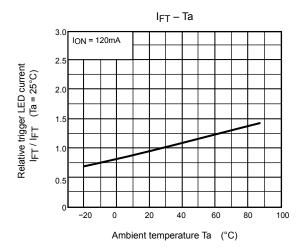


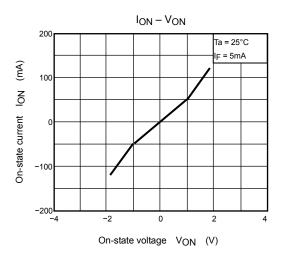


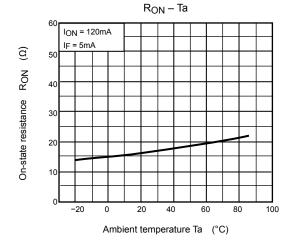


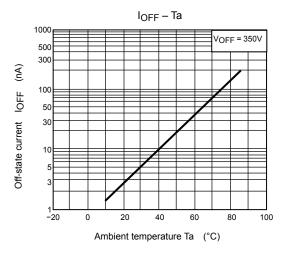


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